

S/N 10/796,514

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	John P. Snyder, et al.	Examiner:	Su C. Kim
Serial No.:	10/796,514	Conf. No.:	1961
		Group Art Unit:	2823
Filed:	March 9, 2004	Docket No.:	6932.14467.05
Title: TRANSISTOR HAVING HIGH DIELECTRIC CONSTANT GATE INSULATING LAYER AND SOURCE AND DRAIN FORMING SCHOTTKY CONTACT WITH SUBSTRATE			

AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Applicants have carefully reviewed and considered the Office Action mailed on July 24, 2008, and the reference cited therewith. Please amend the above-identified patent application as follows. Applicants' Remarks follow the amendments.

This reply is being filed within **four** months of the mailing date of the Office Action. If necessary and not otherwise provided, please consider this a Petition for Extension of Time under 37 CFR 1.136(a) for filing these papers in the above-identified application. Please charge any necessary fee or credit overpayment to Deposit Account No. 502931.